

# CNZ2152 (ON2152)

## Reflective photosensor

Non-contact point SW, object sensing

### Overview

CNZ2152 is a photosensor detecting the change of reflective light in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity Si phototransistor is used as the light detecting element. The two elements are located parallel in the same direction and objects are detected when passing in front of the device.

### Features

- Fast response
- High sensitivity
- High SN ratio

### Applications

- Detection of paper, film and cloth
- Optical mark reading
- Detection of coin and bill
- Detection of position and edge
- Start, end mark detection of magnetic tape

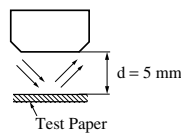
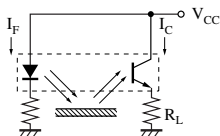
### Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

	Parameter	Symbol	Rating	Unit
Input (Light emitting diode)	Reverse voltage	$V_R$	3	V
	Forward current	$I_F$	100	mA
	Power dissipation *1	$P_D$	150	mW
Output (Photo transistor)	Collector-emitter voltage (Base open)	$V_{CEO}$	20	V
	Emitter-collector voltage (Base open)	$V_{ECO}$	3	V
	Collector current	$I_C$	30	mA
	Collector power dissipation *2	$P_C$	150	mW
	Temperature	Operating ambient temperature	$T_{opr}$	-25 to +85
Storage temperature		$T_{stg}$	-30 to +100	$^\circ\text{C}$

### Electrical-Optical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

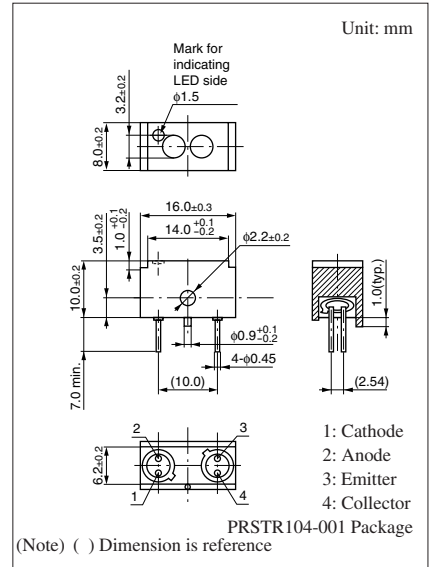
	Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input characteristics	Forward voltage	$V_F$	$I_F = 100 \text{ mA}$		1.25	1.50	V
	Reverse current	$I_R$	$V_R = 5 \text{ V}$			10	$\mu\text{A}$
Output characteristics	Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = 10 \text{ V}$		0.05	2.00	$\mu\text{A}$
Transfer characteristics	Collector current *1	$I_C$ *2	$V_{CC} = 5 \text{ V}, I_F = 20 \text{ mA}, R_L = 100 \Omega$	0.8	3.0		mA
		$I_C$ *3			500		$\mu\text{A}$
	Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_F = 100 \text{ mA}, I_C = 1 \text{ mA}$			0.6	V
	Rise time	$t_r$	$V_{CC} = 10 \text{ V}, I_C = 1 \text{ mA}, R_L = 100 \Omega$		8		$\mu\text{s}$
	Fall time	$t_f$			8		$\mu\text{s}$

- Note) 1. Input and output are handled electrically.  
 2. This product is not designed to withstand radiation  
 3. \*1: Output current measurement circuit (Ambient light is shut off completely)

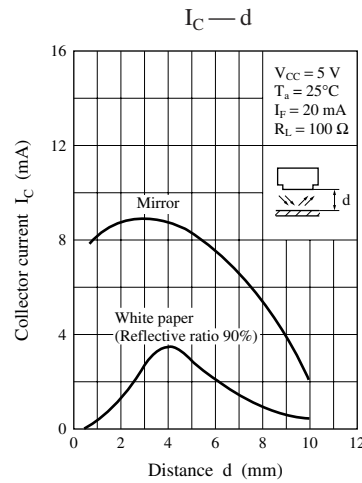
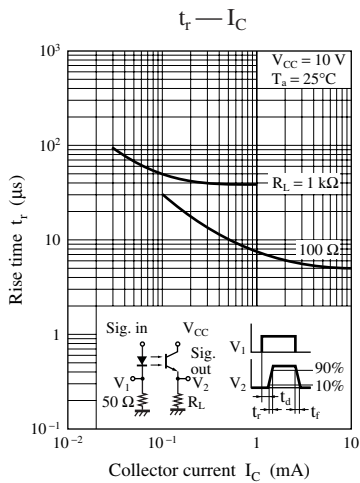
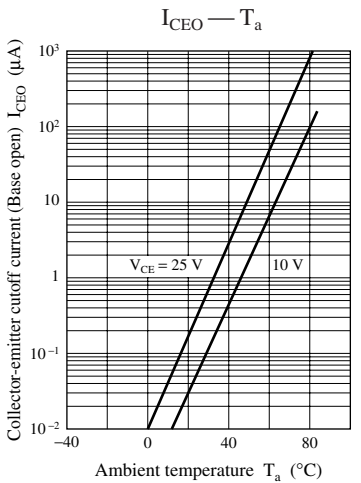
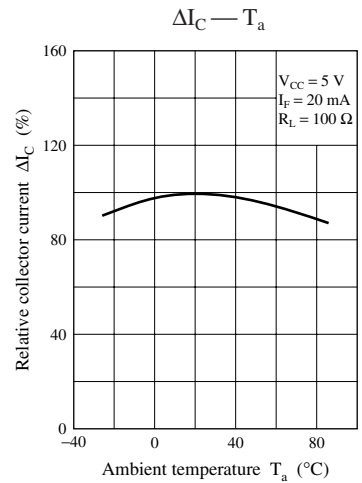
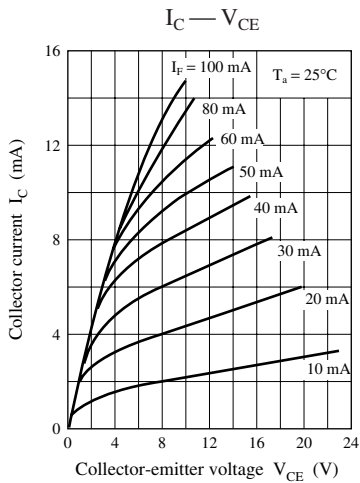
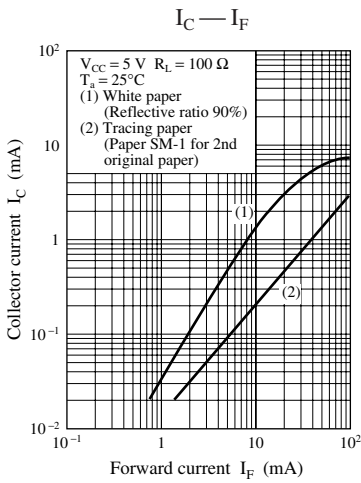
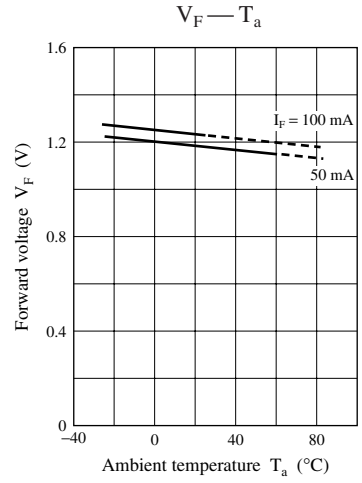
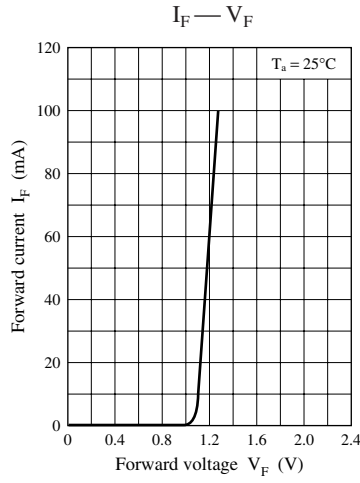
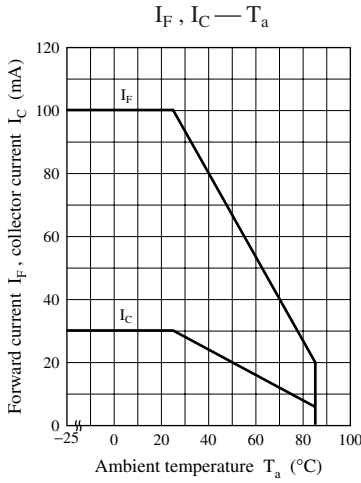


- \*2: White paper (reflective ratio 90%)  
 \*3: Tracing paper (paper SM-1 for 2nd original paper)

Note) The part number in the parenthesis shows conventional part number.



- Note) \*1: Input power derating ratio is  
 2.0 mW/ $^\circ\text{C}$  at  $T_a \geq 25^\circ\text{C}$ .  
 \*2: Output power derating ratio is  
 2.0 mW/ $^\circ\text{C}$  at  $T_a \geq 25^\circ\text{C}$ .



# Caution for Safety

 **DANGER**

## ■ This product contains Gallium Arsenide (GaAs).

GaAs powder and vapor are hazardous to human health if inhaled or ingested. Do not burn, destroy, cut, cleave off, or chemically dissolve the product. Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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